

| Ref # | Hits   | Search Query                            | DBs                                                     | Default Operator | Plurals | Time Stamp       |
|-------|--------|-----------------------------------------|---------------------------------------------------------|------------------|---------|------------------|
| L9    | 4576   | first adj implant\$5                    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:55 |
| L10   | 3884   | second adj implant\$5                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:55 |
| L11   | 19836  | n adj well                              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:56 |
| L12   | 36944  | n adj3 well                             | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:56 |
| L13   | 23548  | n?well                                  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:56 |
| L14   | 24007  | trench near isolation                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:57 |
| L15   | 72     | 9 and (10 same (11 or 12 or 13)) and 14 | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 20:57 |
| L16   | 105371 | threshold adj voltage                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 21:04 |
| L17   | 13773  | "vth"                                   | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 21:07 |
| L18   | 1882   | (11 or 12 or 13) and 14 and (16 or 17)  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | OFF     | 2006/01/30 21:08 |

|          |        |                                     |                                                         |    |     |                  |
|----------|--------|-------------------------------------|---------------------------------------------------------|----|-----|------------------|
| L19      | 337916 | implant\$5                          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 21:14 |
| L20      | 9483   | (11 or 12 or 13) same 19            | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 21:15 |
| L21      | 11379  | (16 or 17) same 19                  | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 21:15 |
| L22      | 767    | 14 and 20 and 21                    | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 21:15 |
| S14<br>9 | 4066   | sacrificial adj oxide               | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:00 |
| S15<br>0 | 105371 | threshold adj voltage               | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:01 |
| S15<br>1 | 7140   | "v.sub.th"                          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:01 |
| S15<br>2 | 337916 | implant\$5                          | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:01 |
| S15<br>3 | 622    | S149 and ((S150 or S151) with S152) | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:18 |
| S15<br>4 | 25409  | trench near2 isolation              | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:17 |

|          |        |                                                                    |                                                         |    |     |                  |
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| S15<br>5 | 289656 | nitride                                                            | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:17 |
| S15<br>6 | 8903   | pad adj oxide                                                      | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 14:17 |
| S15<br>7 | 534    | (S149 or S156) and S155 and S154<br>and ((S150 or S151) with S152) | US-PGPUB;<br>USPAT;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | OFF | 2006/01/30 20:55 |